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KF353

Dual Operational Amplifier (JFET)

Features

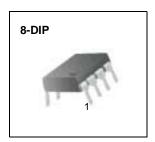
• Internally trimmed offset voltage: 10mV

Low input bias current: 50pA
Wide gain bandwidth: 4MHz
High slew rate: 13V/μs

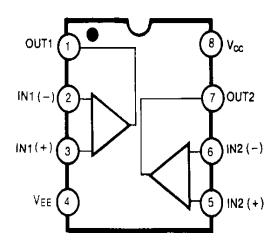
• High Input impedance: $10^{12}\Omega$

Description

The KF353 is a JFET input operational amplifier with an internally compensated input offset voltage. The JFET input device provides wide bandwidth, low input bias currents and offset currents.

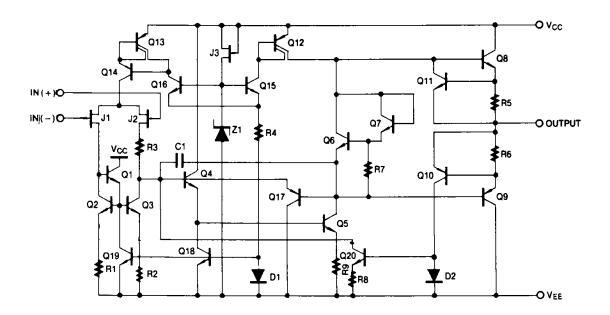


Internal Block Diagram



Schematic Diagram

(One Section Only)



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit	
Power Supply Voltage	Vcc	±18	V	
Differential Input Voltage	VI(DIFF)	30	V	
Input Voltage Range	VI	±15	V	
Output Short Circuit Duration	-	Continuous	-	
Power Dissipation	PD	500	mW	
Operating Temperature Range	Topr	0 ~ +70	°C	
Storage Temperature Range	T _{STG}	-65 ~ +150	°C	

Electrical Characteristics

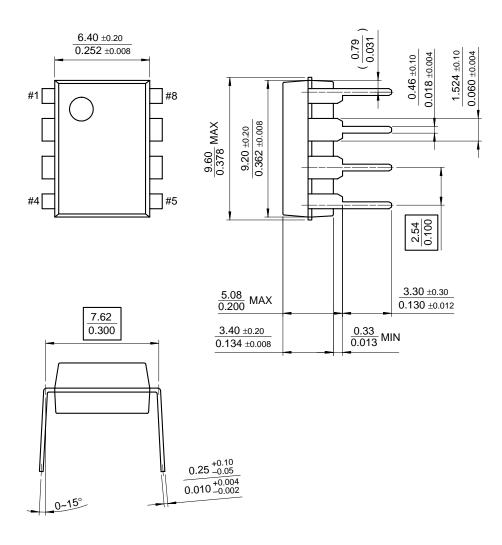
(VCC =+15V, VEE= -15V, TA=25 $^{\circ}$ C, unless otherwise specified)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
Input Offset Voltage	Vio	R _S =10KΩ		-	5.0	10	mV
			0 °C≤TA≤+70 °C	-	-	-	
Input Offset Voltage Drift	ΔV10/ΔΤ	Rs=10KΩ	0 °C≤T _A ≤+70 °C	-	10	-	μV/°C
Input Offset Current	lio			-	25	100	рА
			0 °C≤T _A ≤+70 °C	-	-	4	nA
Input Bias Current	Inua	1		-	50	200	рА
	IBIAS		0 °C≤T _A ≤+70 °C	-	-	8	nA
Input Resistance	Rı	-		-	10 ¹²	-	Ω
Large Signal Voltage Gain	Gv	$VO(P-P) = \pm 10V$		25	100	-	V/mV
		$R_L = 2K\Omega$	0 °C≤T _A ≤+70 °C	15	-	-	-
Output Voltage Swing	VO(P_P)	RL = 10KΩ		±12	±13.5	-	V
Input Voltage Range	VI(R)	-		±11	±15/-12	-	V
Common Mode Rejection Ratio	CMRR	Rs≤10KΩ		70	100	-	dB
Power Supply Rejection Ratio	PSRR	Rs≤10KΩ		70	100	-	dB
Power Supply Current	Icc	-		-	3.6	6.5	mA
Slew Rate	SR	G∨ = 1		-	13	-	V/µS
Gain-Bandwidth Product	GBW	-		-	4	-	MHz
Channel Seperation	CS	f = 1Hz ~ 20KHz (Input referenced)		-	120	-	dB
Equivalent Input Noise Voltage	VNI	$R_S = 100\Omega$ f = 1KHz		-	16	-	nV/ √Hz
Equivalent Input Noise Current	I _{NI}	f = 1KHz		-	0.01	-	pA/ √Hz

Mechanical Dimensions

Package

8-DIP



Ordering Information

Product Number	Package	Operating Temperature		
KF353	8-DIP	0 ~ + 70°C		

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